

PF5102

N-Channel Switch

- This device is designed for low level analog switching, sample and hold circuits and chopper stabized amplifiers.
- Sourced from process 51.
- See J111 for characteristics.



1. Drain 2. Source 3. Gate

Absolute Maximum Ratings * T_A=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{DG}	Drain-Gate Voltage	40	V
V _{GS}	Gate-Source Voltage	-40	V
I _{GF}	Forward Gate Current	50	Α
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ +150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

These ratings are based on a maximum junction temperature of 150 degrees C.
These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics T_A=25°C unless otherwise noted

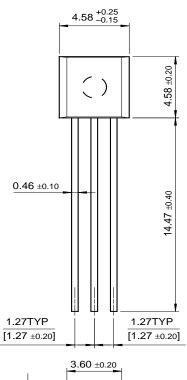
Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Charac	teristics	1 64 15		W.D.	
V _{(BR)GSS}	Gate-Source Breakdwon Voltage	$I_{C} = -1.0 \mu A, V_{DS} = 0$	-40	2.3	V
I _{GSS}	Gate Reverse Current	$V_{GS} = -15V, V_{DS} = 0$ $V_{GS} = -15V, V_{DS} = 0, T_A = 125^{\circ}C$		-1.0 -0.2	nA μA
V _{GS(off)}	Gate-Source Cutoff Voltage	V _{DS} = 15V, I _D = 1.0nA	-0.7	-1.6	V
V _{GS(f)}	Gate-Source Forward Voltage	$I_G = 1.0 \text{mA}, V_{DS} = 0$		1.0	
On Charac	teristics				
I _{DSS}	Zero-Gate Voltage Drain Current *	V _{DS} = 15V, V _{GS} = 0	4.0	20	nA
Small Sign	al Characteristics				
9 _{fs}	Forward Transfer Conductance	$V_{DS} = 15V, V_{GS} = 0, f = 1.0KHz$	11,000		μmhous
g _{oss}	Output Conductance	$V_{DS} = 15V$, $I_D = 500\mu A$, $f = 1.0KHz$		25	μmhous
C _{iss}	Input Capacitace	$V_{DG} = 15V, V_{GS} = 0, f = 1.0MHz$		16	pF
C _{rss}	Reverse Transfer Capacitance	$V_{DG} = 15V, V_{GS} = 0, f = 1.0MHz$	- 11 4	6	pF
Pulse Test: Pul	se Width ≤ 300μs, Duty Cycle ≤ 1.0%				•

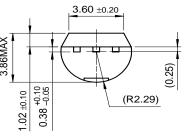
Thermal Characteristics T_A=25°C unless otherwise noted

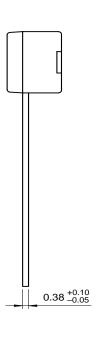
Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

Package Dimensions

TO-92







Dimensions in Millimeters

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